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A: I believe that this is due to the API you're using requesting an id parameter. As per the API Documentation for "GET /api//script/get/scriptdetail/scriptdetail.json" for the api version: if (id) { uri = ""+id } the API takes a scriptid parameter to request more detailed information on that script. If you do a get on their page without passing a scriptid you get their summary page. Here's a sample request for the API without specifying a scriptid: Then when a scriptid is included on the query string it requests more info for that scriptid: The documentation mentions that any of the three request methods can be used to get more information, with the one without a scriptid being the cheapest. 1. Field of the Invention The present invention relates to a manufacturing method of a semiconductor device including an inductor, and more particularly to a manufacturing method of a semiconductor device including an inductor that may operate with good quality when it is manufactured on an SOI substrate. 2. Description of the Prior Art A device operates generally by forming a current between a source and a drain of a transistor with a gate. In an semiconductor device including an inductor, a current is formed between the source and the drain with a gate, and a magnetic field is formed by the current to generate an inductance. A high frequency operation of the inductor can be obtained by the above principle. FIG. 1 is a sectional view of a conventional inductor. Referring to FIG. 1, an inter-level dielectric layer 12 is formed on a silicon substrate 11. Then, a contact hole is formed in the inter-level dielectric layer 12 and a diffusion layer 13 is formed in the silicon substrate 11, and a first metal wire 14 connecting the diffusion layer 13 and the contact hole is formed in the inter-level dielectric layer 12. The first metal wire 14 is connected to an upper metal wire 15 by a via (not shown). c6a93da74d

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